

Dual power Schottky diode

Rev.01 - 15 February 2023

Product data sheet

1. General description

Dual common cathode power Schottky diode in TO220 plastic package.



2. Features and benefits

- High junction temperature up to 175 °C
- · Low forward voltage drop, negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

4. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				200		V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 162 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		5			A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 161 °C; both diodes conducting			10		А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_{F} = 5 \text{ A}; T_{j} = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.83	0.93	V
I _R	reverse current	V _R = 200 V; T _j = 25 °C; per diode; <u>Fig. 7</u>		-	0.03	5	μA

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1	mb	
2	К	cathode		
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode		5

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	U U	Small packing	Package	Package		
	name		method	quantity	version	issue date		
WN3S10S200CT	TO220	WN3S10S200CTQ	Tube	50	SOT78	13-Jun-2008		

7. Marking

Table 4	. Marking	codes
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Type number	Marking codes	
WN3S10S200CT	WN3S10S	
	200CT	

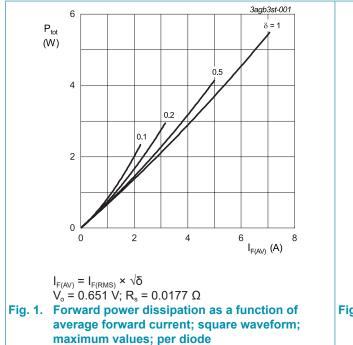
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			200	V
V_{RWM}	crest working reverse voltage			200	V
V _R	reverse voltage	DC		200	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 162 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		5	A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 161 °C; both diodes conducting		10	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(linit)} = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>		130	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		143	A
T _{stg}	storage temperature			-40 to 175	°C
T _j	junction temperature		[1]	-40 to 175	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$



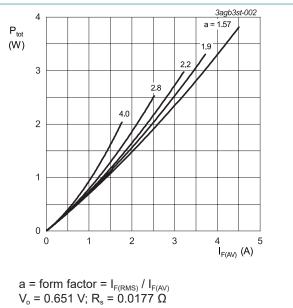
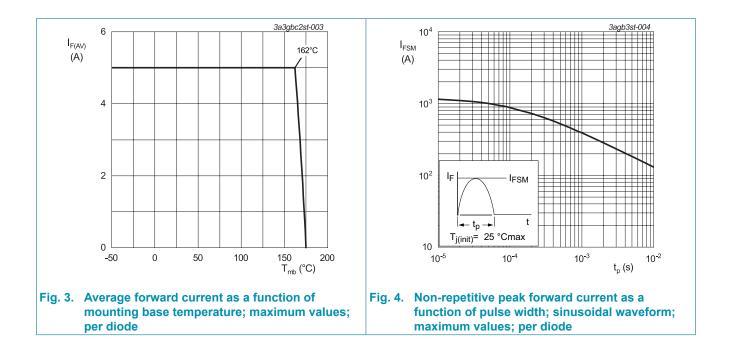


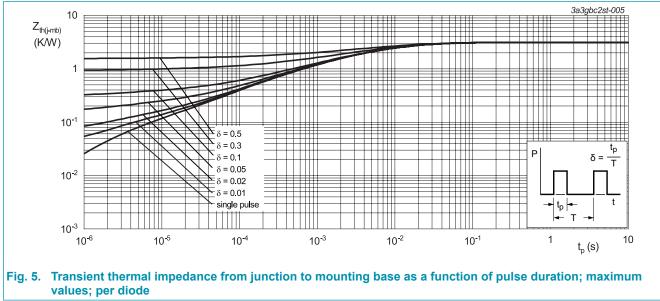
Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

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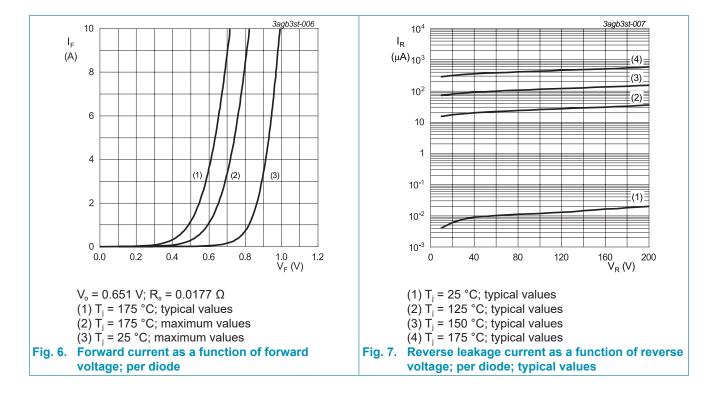
9. Thermal characteristics

Table 6. Th	ermal characteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th}(j\text{-}mb)}$	thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>		-	-	3.1	K/W
		both diodes conducting		-	-	1.7	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

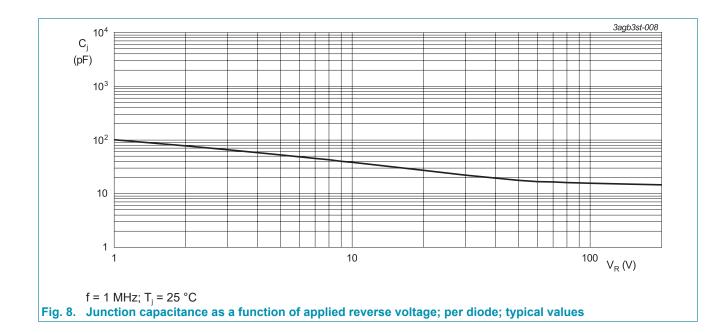


10. Characteristics

Table 7. Cł	naracteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; per diode; <u>Fig. 6</u>		-	0.83	0.93	V
		$I_F = 5 \text{ A}; T_j = 125 \text{ °C}; \text{ per diode}$		-	0.70	-	V
		$I_F = 5 \text{ A}; T_j = 175 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.64	0.74	V
I _R reverse current		V _R = 200 V; T _j = 25 °C; per diode; <u>Fig. 7</u>		-	0.03	5	μA
		V _R = 200 V; T _j = 125 °C; per diode; <u>Fig. 7</u>		-	0.04	-	mA

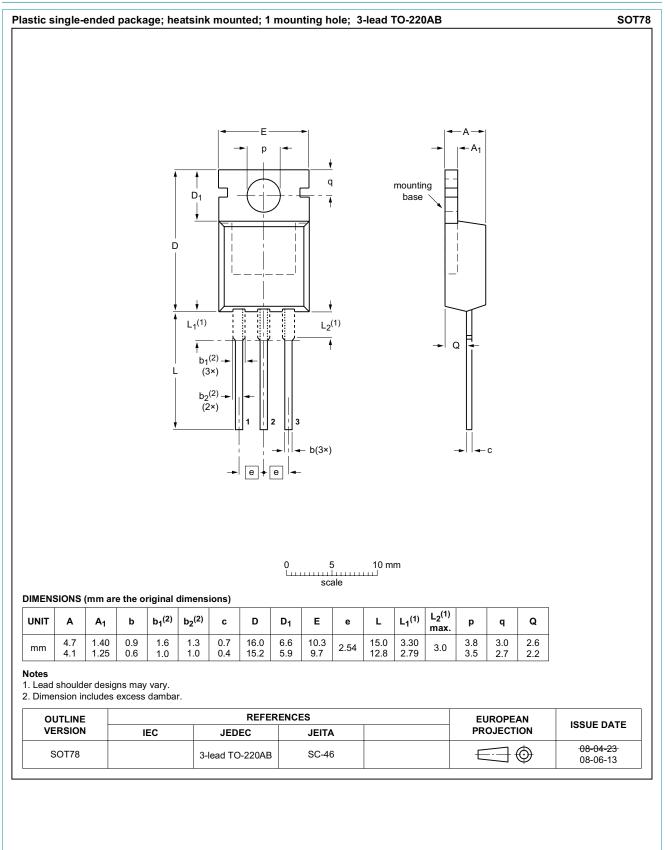


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11. Package outline



Dual power Schottky diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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